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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR NP88N03KDG

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The NP88N03KDG is N-channel MOS Field Effect
Transistor designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	PACKAGE		
NP88N03KDG	TO-263 (MP-25ZK)		

FEATURES

- Channel temperature 175 degree rating
- Super low on-state resistance

 $R_{\text{DS(on)1}}$ = 2.4 m Ω MAX. (Vgs = 10 V, Ip = 44 A)

 $R_{DS(on)2}$ = 3.9 m Ω MAX. (Vgs = 4.5 V, ID = 44 A)

- Low Ciss: Ciss = 9000 pF TYP. (VDS = 25 V)
- 4.5 V gate drive type

(TO-263)



ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V _{GS} = 0 V)	VDSS	30	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	±88	Α
Drain Current (pulse) Note1	D(pulse)	±352	Α
Total Power Dissipation (T _A = 25°C)	P _{T1}	1.8	W
Total Power Dissipation (Tc = 25°C)	P _{T2}	200	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	-55 to +175	°C
Repetitive Avalanche Current Note2	lar	59	Α
Repetitive Avalanche Energy Note2	Ear	348	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Tch \leq 150°C, VdD = 15 V, Rg = 25 Ω , Vgs = 20 \rightarrow 0 V

THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	0.75	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

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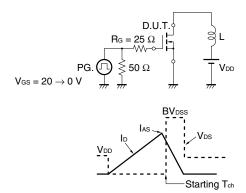


ELECTRICAL CHARACTERISTICS (TA = 25°C)

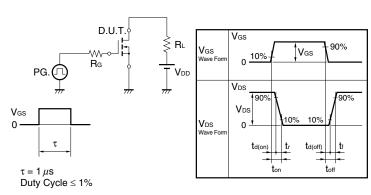
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 30 V, V _{GS} = 0 V			1	μΑ
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate to Source Threshold Voltage Note	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	1.5	2.0	2.5	V
Forward Transfer Admittance Note	y fs	V _{DS} = 10 V, I _D = 44 A	37	75		S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = 10 V, I _D = 44 A		1.9	2.4	mΩ
	RDS(on)2	V _{GS} = 4.5 V, I _D = 44 A		2.4	3.9	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V		9000	13500	pF
Output Capacitance	Coss	V _{GS} = 0 V		1100	1650	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		740	1340	pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 15 V, I _D = 44 A		35	80	ns
Rise Time	tr	V _{GS} = 10 V		1100	2750	ns
Turn-off Delay Time	t _{d(off)}	R _G = 0 Ω		125	250	ns
Fall Time	t _f			23	60	ns
Total Gate Charge	Q _G	V _{DD} = 24 V		165	250	nC
Gate to Source Charge	Qgs	V _{GS} = 10 V		26		nC
Gate to Drain Charge	Q _{GD}	I _D = 88 A		50		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 88 A, V _{GS} = 0 V		0.9	1.5	V
Reverse Recovery Time	trr	I _F = 88 A, V _{GS} = 0 V		60		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		78		nC

Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY



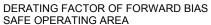
TEST CIRCUIT 2 SWITCHING TIME

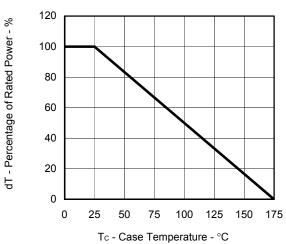


TEST CIRCUIT 3 GATE CHARGE

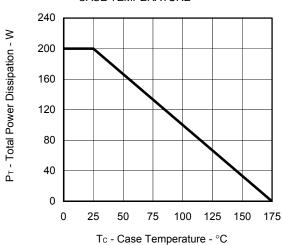
$$\begin{array}{c|c} D.U.T \\ \hline \\ I_G = 2 \text{ mA} \\ \hline \\ \hline \\ V_{DD} \\ \hline \end{array}$$

TYPICAL CHARACTERISTICS (T_A = 25°C)

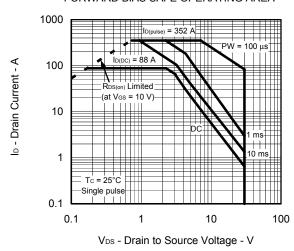




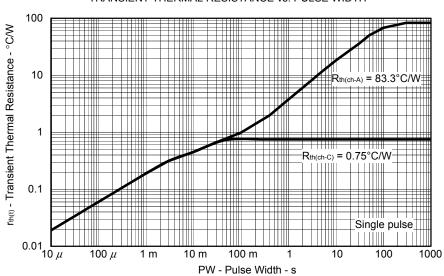
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

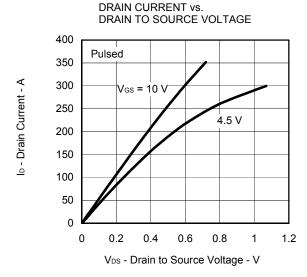


FORWARD BIAS SAFE OPERATING AREA

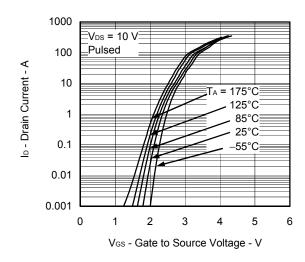


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

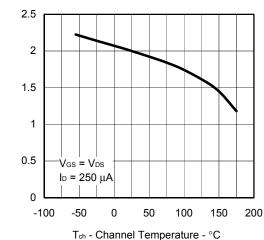




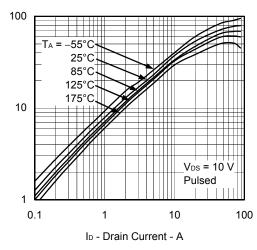




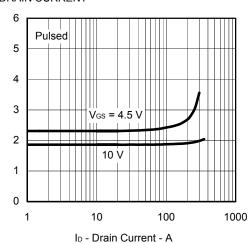
GATE SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE



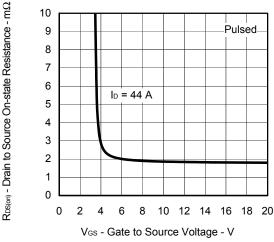
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



 $R_{DS(on)}$ - Drain to Source On-state Resistance - $m\Omega$

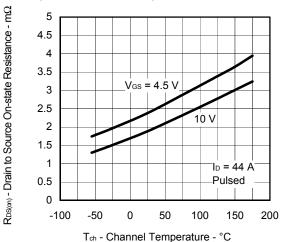
Vos(th) - Gate to Source Threshold Voltage - V

| yfs | - Forward Transfer Admittance - S

V_{GS} = 0 V

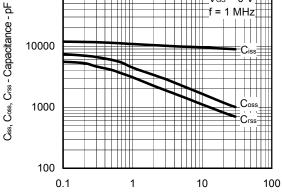
f = 1 MHz

DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



10000

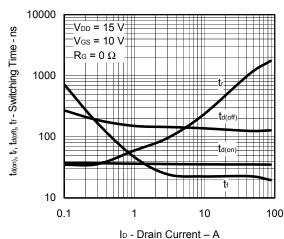
100000



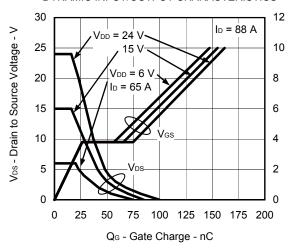
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

VDS - Drain to Source Voltage - V

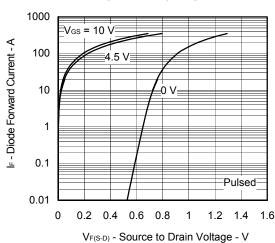
SWITCHING CHARACTERISTICS



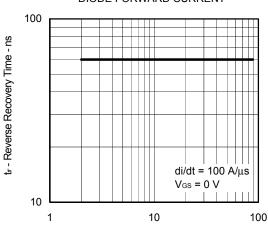
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

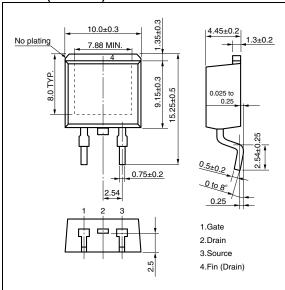


IF - Diode Forward Current - A

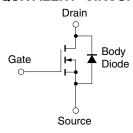
Ves - Gate to Source Voltage - V

PACKAGE DRAWING (Unit: mm)

TO-263 (MP-25ZK)



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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